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# **BQ28Z610 Impedance Track™ Gas Gauge and Protection Solution for 1-Series to 2-Series Cell Li-Ion Battery Packs**

## **1 Features**

- Autonomous battery charging control, using a dedicated MASTER mode I<sup>2</sup>C interface
- Cell balancing with an internal bypass to optimize battery health
- A high-side protection N-CH FET drive enables serial bus communication during fault conditions
- Programmable protection levels for voltage, current, and temperature
- Analog front-end with two independent ADCs
	- Support for simultaneous current and voltage sampling
	- High-accuracy coulomb counter with input offset error < 1 µV (typical)
- Supports down to 1-mΩ current sense resistor while capable of 1-mA current measurement
- Supports battery trip point (BTP) function for Windows® integration
- SHA-1 authentication responder for increased battery pack security
- 400-kHz I<sup>2</sup>C bus communications interface for high-speed programming and data access
- Compact 12-pin VSON package (DRZ)

## **2 Applications**

- [Tablet computing](http://www.ti.com/applications/personal-electronics/tablets/overview.html)
- [Portable and wearable health devices](http://www.ti.com/applications/industrial/medical/overview.html)
- [Portable audio devices](http://www.ti.com/applications/personal-electronics/portable-electronics/overview.html)
	- [Wireless \(Bluetooth\) speakers](http://www.ti.com/solution/wireless-speaker)



## **3 Description**

The Texas Instruments BQ28Z610 device is a highly integrated, accurate, 1-series to 2-series cell gas gauge and protection solution, enabling autonomous charger control and cell balancing.

The BQ28Z610 device enables autonomous charge control through Master Mode I2C broadcasts of charging current and voltage information, eliminating software overhead that is typically incurred by the system's host controller.

The BQ28Z610 device provides a fully integrated pack-based solution with a flash programmable custom reduced instruction-set CPU (RISC), safety protection, and authentication for 1-series to 2-series cell Li-ion and Li-polymer battery packs.

The BQ28Z610 gas gauge communicates through an I2C compatible interface and combines an ultra-low-power, high-speed TI BQBMP processor, high-accuracy analog measurement capabilities, integrated flash memory, an array of peripheral and communication ports, an N-CH FET drive, and a SHA-1 Authentication transform responder into a complete, high-performance battery management solution.

#### **Device Information**



(1) For all available packages, see the orderable addendum at the end of the data sheet.



**Block Diagram**



# **Table of Contents**





## **4 Revision History**



## **5 Description (Continued)**

The BQ28Z610 device provides an array of battery and system safety functions, including overcurrent in discharge, short circuit in charge, and short circuit in discharge protection for the battery, as well as FET protection for the N-channel FETs, internal AFE watchdog, and cell balancing. Through firmware, the devices can provide a larger array of features including protection against overvoltage, undervoltage, overtemperature, and more.

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## **6 Pin Configuration and Functions**



#### **Table 6-1. Pin Functions**



(1) P = Power Connection, O = Digital Output, AI = Analog Input, I = Digital Input, I/O = Digital Input/Output



## <span id="page-3-0"></span>**7 Specifications**

## **7.1 Absolute Maximum Ratings**

Over operating free-air temperature range (unless otherwise noted) $(1)$ 



(1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute–maximum–rated conditions for extended periods may affect device reliability.

## **7.2 ESD Ratings**



(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

## **7.3 Recommended Operating Conditions**

Typical values stated where T<sub>A</sub> = 25°C and VCC = 7.2 V, Min/Max values stated where T<sub>A</sub> = –40°C to 85°C and VCC = 2.2 V to 26 V (unless otherwise noted)



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## **7.4 Thermal Information**



(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report, [SPRA953](https://www.ti.com/lit/pdf/SPRA953).

## **7.5 Supply Current**

Typical values stated where T<sub>A</sub> = 25°C and VCC = 7.2 V, Min/Max values stated where T<sub>A</sub> = –40°C to 85°C and VCC = 2.2 V to 7.6 V (unless otherwise noted)



(1) Dependent on the use of the correct firmware (FW) configuration

## **7.6 Power Supply Control**

Typical values stated where  $T_A$  = 25°C and VCC = 7.2 V, Min/Max values stated where  $T_A$  = -40°C to 85°C and VCC = 2.2 V to 7.6 V (unless otherwise noted)



## **7.7 Low-Voltage General Purpose I/O, TS1**

Typical values stated where T<sub>A</sub> = 25°C and VCC = 7.2 V, Min/Max values stated where T<sub>A</sub> = –40°C to 85°C and VCC = 2.2 V to 7.6 V (unless otherwise noted)



<span id="page-5-0"></span>Typical values stated where  $T_A$  = 25°C and VCC = 7.2 V, Min/Max values stated where  $T_A$  = -40°C to 85°C and VCC = 2.2 V to 7.6 V (unless otherwise noted)



## **7.8 Power-On Reset (POR)**

Typical values stated where  $T_A$  = 25°C and VCC = 7.2 V, Min/Max values stated where  $T_A$  = -40°C to 85°C and VCC = 2.2 V to 7.6 V (unless otherwise noted)



## **7.9 Internal 1.8-V LDO**

Typical values stated where  $T_A$  = 25°C and VCC = 7.2 V, Min/Max values stated where  $T_A$  = -40°C to 85°C and VCC = 2.2 V to 7.6 V (unless otherwise noted)



## **7.10 Current Wake Comparator**

Typical values stated where  $T_A$  = 25°C and VCC = 7.2 V, Min/Max values stated where  $T_A$  = -40°C to 85°C and VCC = 2.2 V to 7.6 V (unless otherwise noted)



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## **7.11 Coulomb Counter**

Typical values stated where T<sub>A</sub> = 25°C and VCC = 7.2 V, Min/Max values stated where T<sub>A</sub> = –40°C to 85°C and VCC = 2.2 V to 7.6 V (unless otherwise noted)



## **7.12 ADC Digital Filter**

Typical values stated where  $T_A$  = 25°C and VCC = 7.2 V, Min/Max values stated where  $T_A$  = -40°C to 85°C and VCC = 2.2 V to 7.6 V (unless otherwise noted)



## **7.13 ADC Multiplexer**

Typical values stated where  $T_A$  = 25°C and VCC = 7.2 V, Min/Max values stated where  $T_A$  = -40°C to 85°C and VCC = 2.2 V to 7.6 V (unless otherwise noted)



## **7.14 Cell Balancing Support**

Typical values stated where T<sub>A</sub> = 25°C and VCC = 7.2 V, Min/Max values stated where T<sub>A</sub> = –40°C to 85°C and VCC = 2.2 V to 7.6 V (unless otherwise noted)



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## <span id="page-7-0"></span>**7.15 Internal Temperature Sensor**

Typical values stated where T<sub>A</sub> = 25°C and VCC = 7.2 V, Min/Max values stated where T<sub>A</sub> = –40°C to 85°C and VCC = 2.2 V to 7.6 V (unless otherwise noted)



(1) Assured by design

## **7.16 NTC Thermistor Measurement Support**

Typical values stated where  $T_A$  = 25°C and VCC = 7.2 V, Min/Max values stated where  $T_A$  = -40°C to 85°C and VCC = 2.2 V to 7.6 V (unless otherwise noted)



## **7.17 High-Frequency Oscillator**

Typical values stated where  $T_A$  = 25°C and VCC = 7.2 V, Min/Max values stated where  $T_A$  = -40°C to 85°C and VCC = 2.2 V to 7.6 V (unless otherwise noted)



## **7.18 Low-Frequency Oscillator**

Typical values stated where  $T_A = 25^\circ$ C and VCC = 7.2 V, Min/Max values stated where  $T_A = -40^\circ$ C to 85°C and VCC = 2.2 V to 7.6 V (unless otherwise noted)



## **7.19 Voltage Reference 1**

Typical values stated where  $T_A = 25^\circ$ C and VCC = 7.2 V, Min/Max values stated where  $T_A = -40^\circ$ C to 85°C and VCC = 2.2 V to 7.6 V (unless otherwise noted)



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Typical values stated where  $T_A$  = 25°C and VCC = 7.2 V, Min/Max values stated where  $T_A$  = -40°C to 85°C and VCC = 2.2 V to 7.6 V (unless otherwise noted)



## **7.20 Voltage Reference 2**

Typical values stated where T<sub>A</sub> = 25°C and VCC = 7.2 V, Min/Max values stated where T<sub>A</sub> = –40°C to 85°C and VCC = 2.2 V to 7.6 V (unless otherwise noted)



## **7.21 Instruction Flash**

Typical values stated where  $T_A$  = 25°C and VCC = 7.2 V, Min/Max values stated where  $T_A$  = -40°C to 85°C and VCC = 2.2 V to 7.6 V (unless otherwise noted)



## **7.22 Data Flash**

Typical values stated where  $T_A$  = 25°C and VCC = 7.2 V, Min/Max values stated where  $T_A$  = -40°C to 85°C and VCC = 2.2 V to 7.6 V (unless otherwise noted)





## <span id="page-9-0"></span>**7.23 Current Protection Thresholds**

Typical values stated where  $T_A$  = 25°C and VCC = 7.2 V, Min/Max values stated where  $T_A$  = -40°C to 85°C and VCC = 2.2 V to 7.6 V (unless otherwise noted)



## **7.24 Current Protection Timing**

Typical values stated where T<sub>A</sub> = 25°C and VCC = 7.2 V, Min/Max values stated where T<sub>A</sub> = –40°C to 85°C and VCC = 2.2 V to 7.6 V (unless otherwise noted)



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Typical values stated where  $T_A$  = 25°C and VCC = 7.2 V, Min/Max values stated where  $T_A$  = -40°C to 85°C and VCC = 2.2 V to 7.6 V (unless otherwise noted)



## **7.25 N-CH FET Drive (CHG, DSG)**

Typical values stated where  $T_A$  = 25°C and VCC = 7.2 V, Min/Max values stated where  $T_A$  = -40°C to 85°C and VCC = 2.2 V to 7.6 V (unless otherwise noted)



## **7.26 I <sup>2</sup>C Interface I/O**

Typical values stated where  $T_A$  = 25°C and VCC = 7.2 V, Min/Max values stated where  $T_A$  = -40°C to 85°C and VCC = 2.2 V to 7.6 V (unless otherwise noted)





## <span id="page-11-0"></span>**7.27 I <sup>2</sup>C Interface Timing**

Typical values stated where T<sub>A</sub> = 25°C and VCC = 7.2 V, Min/Max values stated where T<sub>A</sub> = –40°C to 85°C and VCC = 2.2 V to 7.6 V (unless otherwise noted)







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## **7.28 Typical Characteristics**



**[BQ28Z610](https://www.ti.com/product/BQ28Z610)** SLUSAS3D – APRIL 2014 – REVISED JUNE 2021 **[www.ti.com](https://www.ti.com)**











## <span id="page-15-0"></span>**8 Detailed Description**

## **8.1 Overview**

The BQ28Z610 gas gauge is a fully integrated battery manager that employs flash-based firmware and integrated hardware protection to provide a complete solution for battery-stack architectures composed of 1-series to 2-series cells. The BQ28Z610 device interfaces with a host system through an  $1<sup>2</sup>C$  protocol. Highperformance, integrated analog peripherals enable support for a sense resistor down to 1 mΩ and simultaneous current/voltage data conversion for instant power calculations. The following sections detail all of the major component blocks included as part of the BQ28Z610 device.

### **8.2 Functional Block Diagram**

The *Functional Block Diagram* depicts the analog (AFE) and digital (AGG) peripheral content in the BQ28Z610 device.



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#### **8.3 Feature Description**

#### **8.3.1 Battery Parameter Measurements**

The BQ28Z610 device measures cell voltage and current simultaneously, and also measures temperature to calculate the information related to remaining capacity, full charge capacity, state-of-health, and other gauging parameters.

#### *8.3.1.1 BQ28Z610 Processor*

The BQ28Z610 device uses a custom TI-proprietary processor design that features a Harvard architecture and operates at frequencies up to 4.2 MHz. Using an adaptive, three-stage instruction pipeline, the BQ28Z610 processor supports variable instruction length of 8, 16, or 24 bits.

#### **8.3.2 Coulomb Counter (CC)**

The first ADC is an integrating converter designed specifically for coulomb counting. The converter resolution is a function of its full-scale range and number of bits, yielding a 3.74-µV resolution.

#### **8.3.3 CC Digital Filter**

The CC digital filter generates a 16-bit conversion value from the delta-sigma CC front-end. Its FIR filter uses the LFO clock output, which allows it to stop the HFO clock during conversions. New conversions are available every 250 ms while CCTL[CC\_ON] = 1. Proper use of this peripheral requires turning on the CC modulator in the AFE.

#### **8.3.4 ADC Multiplexer**

The ADC multiplexer provides selectable connections to the VCx inputs, TS1 inputs, internal temperature sensor, internal reference voltages, internal 1.8-V regulator, PACK input, and VSS ground reference input. In addition, the multiplexer can independently enable the TS1 input connection to the internal thermistor biasing circuitry, and also enables the user to short the multiplexer inputs for test and calibration purposes.

#### **8.3.5 Analog-to-Digital Converter (ADC)**

The second ADC is a 16-bit delta-sigma converter designed for general-purpose measurements. The ADC automatically scales the input voltage range during sampling based on channel selection. The converter resolution is a function of its full-scale range and number of bits, yielding a 38-µV resolution. The default conversion time of the ADC is 31.25 ms, but is user-configurable down to 1.95 ms. Decreasing the conversion time presents a tradeoff between conversion speed and accuracy, as the resolution decreases for faster conversion times.

#### **8.3.6 ADC Digital Filter**

The ADC digital filter generates a 24-bit conversion result from the delta-sigma ADC front end. Its FIR filter uses the LFO clock, which allows it to stop the HFO clock during conversions. The ADC digital filter is capable of providing two 24-bit results: one result from the delta-sigma ADC front-end and a second synchronous result from the delta-sigma CC front-end.

#### **8.3.7 Internal Temperature Sensor**

An internal temperature sensor is available on the BQ28Z610 device to reduce the cost, power, and size of the external components necessary to measure temperature. It is available for connection to the ADC using the multiplexer, and is ideal for quickly determining pack temperature under a variety of operating conditions.

#### **8.3.8 External Temperature Sensor Support**

The TS1 input is enabled with an internal 18-kΩ (Typ.) linearization pullup resistor to support using a 10-kΩ (25°C) NTC external thermistor, such as the Semitec 103AT-2. The NTC thermistor should be connected between VSS and the individual TS1 pin. The ADC, through its input multiplexer, then takes the analog measurement. If a different thermistor type is required, changes to configurations may be required.

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**Figure 8-1. External Thermistor Biasing**

#### **8.3.9 Power Supply Control**

The BQ28Z610 device manages its supply voltage dynamically according to operating conditions. When  $V_{VC2}$  $>$  V<sub>SWITCHOVER</sub> + V<sub>HYS</sub>, the AFE connects an internal switch to BAT and uses this pin to supply power to its internal 1.8-V LDO, which subsequently powers all device logic and flash operations. Once VC2 decreases to  $V_{VC2}$  <  $V_{SWITCHOVER}$ , the AFE disconnects its internal switch from VC2 and connects another switch to PACK, allowing sourcing of power from a charger (if present). An external capacitor connected to PBI provides a momentary supply voltage to help guard against system brownouts due to transient short-circuit or overload events that pull VC2 below V<sub>SWITCHOVER-</sub>.

#### **8.3.10 Power-On Reset**

In the event of a power-cycle, the BQ28Z610 AFE holds its internal RESET output pin high for t<sub>RST</sub> duration to allow its internal 1.8-V LDO and LFO to stabilize before running the AGG. The AFE enters power-on reset when the voltage at V<sub>REG</sub> falls below V<sub>REGIT</sub> and exits reset when V<sub>REG</sub> rises above V<sub>REGIT</sub> + V<sub>HYS</sub> for t<sub>RST</sub> time. After t<sub>RST</sub>, the BQ28Z610 AGG will write its trim values to the AFE.



**Figure 8-2. POR Timing Diagram**

#### **8.3.11 Bus Communication Interface**

The BQ28Z610 device has an I<sup>2</sup>C bus communication interface. This device has the option to broadcast information to a smart charger to provide key information to adjust the charging current and charging voltage based on the temperature or individual cell voltages.



#### **CAUTION**

If the device is configured as a single-master architecture (an application processor) and an occasional NACK is detected in the operation, the master can resend the transaction. However, in a multi-master architecture, an incorrect ACK leading to accidental loss of bus arbitration can cause a master to wait incorrectly for another master to clear the bus. If this master does not get a bus-free signal, then it must have in place a method to look for the bus and assume it is free after some period of time. Also, if possible, set the clock speed to be 100 kHz or less to significantly reduce the issue described above for multi-mode operation.

#### **8.3.12 Cell Balancing Support**

The integrated cell balancing FETs included in the BQ28Z610 device enable the AFE to bypass cell current around a given cell or numerous cells to effectively balance the entire battery stack. External series resistors placed between the cell connections and the VCx input pins set the balancing current magnitude. The cell balancing circuitry can be enabled or disabled through the *CELL\_BAL\_DET[CB2, CB1]* control register. Series input resistors between 100 Ω and 1 kΩ are recommended for effective cell balancing.



**Figure 8-3. Internal Cell Balancing**

## **8.3.13 N-Channel Protection FET Drive**

The BQ28Z610 device controls two external N-Channel MOSFETs in a back-to-back configuration for battery protection. The charge (CHG) and discharge (DSG) FETs are automatically disabled if a safety fault (AOLD, ASSC, ASCD, SOV) is detected, and can also be manually turned off using *AFE\_CONTROL[CHGEN, DSGEN]*  = 0, 0. When the gate drive is disabled, an internal circuit discharges CHG to VC2 and DSG to PACK.

## **8.3.14 Low Frequency Oscillator**

The BQ28Z610 AFE includes a low frequency oscillator (LFO) running at 262.144 kHz. The AFE monitors the LFO frequency and indicates a failure through **LATCH STATUS[LFO]** if the output frequency is much lower than normal.

## **8.3.15 High Frequency Oscillator**

The BQ28Z610 AGG includes a high frequency oscillator (HFO) running at 16.78 MHz. It is synthesized from the LFO output and scaled down to 8.388 MHz with 50% duty cycle.

## **8.3.16 1.8-V Low Dropout Regulator**

The BQ28Z610 AFE contains an integrated 1.8-V LDO that provides regulated supply voltage for the device CPU and internal digital logic.

## **8.3.17 Internal Voltage References**

The BQ28Z610 AFE provides two internal voltage references with  $V_{RFF1}$ , used by the ADC and CC, while  $V_{RFF2}$ is used by the LDO, LFO, current wake comparator, and OCD/SCC/SCD1/SCD2 current protection circuitry.



#### **8.3.18 Overcurrent in Discharge Protection**

The overcurrent in discharge (OCD) function detects abnormally high current in the discharge direction. The overload in discharge threshold and delay time are configurable through the OCD\_CONTROL register. The thresholds and timing can be fine-tuned even further, based on a sense resistor with lower resistance or wider tolerance through the PROTECTION\_CONTROL register. The detection circuit also incorporates a filtered delay before disabling the CHG and DSG FETs. When an OCD event occurs, the *LATCH\_STATUS[OCD]* bit is set to 1 and is latched until it is cleared and the fault condition has been removed.

#### **8.3.19 Short-Circuit Current in Charge Protection**

The short-circuit current in charge (SCC) function detects catastrophic current conditions in the charge direction. The short-circuit in charge threshold and delay time are configurable through the SCC\_CONTROL register. The thresholds and timing can be fine-tuned even further based on a sense resistor with lower resistance or wider tolerance through the PROTECTION\_CONTROL register. The detection circuit also incorporates a blanking delay before disabling the CHG and DSG FETs. When an SCC event occurs, the *LATCH\_STATUS[SCC]* bit is set to 1 and is latched until it is cleared and the fault condition has been removed.

#### **8.3.20 Short-Circuit Current in Discharge 1 and 2 Protection**

The short-circuit current in discharge (SCD) function detects catastrophic current conditions in the discharge direction. The short-circuit in discharge thresholds and delay times are configurable through the SCD1 CONTROL and SCD2 CONTROL registers. The thresholds and timing can be fine-tuned even further, based on a sense resistor with lower resistance or wider tolerance through the PROTECTION CONTROL register. The detection circuit also incorporates a blanking delay before disabling the CHG and DSG FETs. When an SCD event occurs, the *LATCH\_STATUS[SCD1]* or *LATCH\_STATUS[SCD2]* bit is set to 1 and is latched until it is cleared and the fault condition has been removed.

#### **8.3.21 Primary Protection Features**

The BQ28Z610 gas gauge supports the following battery and system level protection features, which can be configured using firmware:

- Cell Undervoltage Protection
- Cell Overvoltage Protection
- Overcurrent in CHARGE Mode Protection
- Overcurrent in DISCHARGE Mode Protection
- Overload in DISCHARGE Mode Protection
- Short Circuit in CHARGE Mode Protection
- Overtemperature in CHARGE Mode Protection
- Overtemperature in DISCHARGE Mode Protection
- Precharge Timeout Protection
- Fast Charge Timeout Protection

#### **8.3.22 Gas Gauging**

This device uses the Impedance Track™ technology to measure and determine the available charge in battery cells. The accuracy achieved using this method is better than 1% error over the lifetime of the battery. There is no full charge/discharge learning cycle required. See the *[Theory and Implementation of Impedance Track](https://www.ti.com/lit/pdf/SLUA364) [Battery Fuel-Gauging Algorithm Application Report](https://www.ti.com/lit/pdf/SLUA364)* (SLUA364B) for further details.

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#### **8.3.23 Charge Control Features**

This device supports charge control features, such as:

- Reports charging voltage and charging current based on the active temperature range—JEITA temperature ranges T1, T2, T3, T4, T5, and T6
- Provides more complex charging profiles, including sub-ranges within a standard temperature range
- Reports the appropriate charging current required for constant current charging and the appropriate charging voltage needed for constant voltage charging to a smart charger, using the bus communication interface
- Selects the chemical state-of-charge of each battery cell using the Impedance Track method, and reduces the voltage difference between cells when cell balancing multiple cells in a series
- Provides pre-charging/zero-volt charging
- Employs charge inhibit and charge suspend if battery pack temperature is out of programmed range
- Reports charging faults and indicates charge status from charge and discharge alarms

#### **8.3.24 Authentication**

This device supports security by:

- Authentication by the host using the SHA-1 method
- The gas gauge requires SHA-1 authentication before the device can be unsealed or allow full access.

#### **8.4 Device Functional Modes**

This device supports three modes, but the current consumption varies, based on firmware control of certain functions and modes of operation:

- NORMAL mode: In this mode, the device performs measurements, calculations, protections, and data updates every 250-ms intervals. Between these intervals, the device is operating in a reduced power stage to minimize total average current consumption.
- SLEEP mode: In this mode, the device performs measurements, calculations, protections, and data updates in adjustable time intervals. Between these intervals, the device is operating in a reduced power stage to minimize total average current consumption.
- SHUTDOWN mode: The device is completely disabled.

#### **8.4.1 Lifetime Logging Features**

The device supports data logging of several key parameters for warranty and analysis:

- Maximum and Minimum Cell Temperature
- Maximum Current in CHARGE or DISCHARGE Mode
- Maximum and Minimum Cell Voltages

#### **8.4.2 Configuration**

The device supports accurate data measurements and data logging of several key parameters.

#### *8.4.2.1 Coulomb Counting*

The device uses an integrating delta-sigma analog-to-digital converter (ADC) for current measurement. The ADC measures charge/discharge flow of the battery by measuring the voltage across a very small external sense resistor. The integrating ADC measures a bipolar signal from a range of –100 mV to 100 mV, with a positive value when  $V_{(SRP)} - V_{(SRN)}$ , indicating charge current and a negative value indicating discharge current. The integration method uses a continuous timer and internal counter, which has a rate of 0.65 nVh.

#### *8.4.2.2 Cell Voltage Measurements*

The BQ28Z610 measures the individual cell voltages at 250-ms intervals using an ADC. This measured value is internally scaled for the ADC and is calibrated to reduce any errors due to offsets. This data is also used for calculating the impedance of the individual cell for Impedance Track gas gauging.



#### *8.4.2.3 Current Measurements*

The current measurement is performed by measuring the voltage drop across the external sense resistor (1 mΩ to 3 mΩ) and the polarity of the differential voltage determines if the cell is in the CHARGE or DISCHARGE mode.

#### *8.4.2.4 Auto Calibration*

The auto-calibration feature helps to cancel any voltage offset across the SRP and SRN pins for accurate measurement of the cell voltage, charge/discharge current, and thermistor temperature. The auto-calibration is performed when there is no communication activity for a minimum of 5 s on the bus lines.

#### *8.4.2.5 Temperature Measurements*

This device has an internal sensor for on-die temperature measurements, and supports external temperature measurements through the external NTC on the TS1 pin. These two measurements are individually enabled and configured.

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## **9 Applications and Implementation**

#### **Note**

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

#### **9.1 Application Information**

The BQ28Z610 gas gauge is a primary protection device that can be used with a 1-series to 2-series Li-ion/Li polymer battery pack. To implement and design a comprehensive set of parameters for a specific battery pack, the user needs [Battery Management Studio \(BQSTUDIO\),](http://www.ti.com/tool/bqStudio) which is a graphical user-interface tool installed on a PC during development. The firmware installed in the product has default values, which are summarized in the *[BQ28Z610 Technical Reference Manual](https://www.ti.com/lit/pdf/SLUUA65)* (SLUUA65) for this product. Using the BQSTUDIO tool, these default values can be changed to cater to specific application requirements during development once the system parameters, such as fault trigger thresholds for protection, enable/disable of certain features for operation, configuration of cells, chemistry that best matches the cell used, and more are known. This data can be referred to as the "golden image."

#### **9.2 Typical Applications**

Figure 9-1 shows the BQ28Z610 application schematic for the 2-series configuration. [Figure 9-2](#page-23-0) shows a wireless (Bluetooth) speaker application block diagram.



Note: The input filter capacitors of 0.1 µF for the SRN and SRP pins must be located near the pins of the device.



<span id="page-23-0"></span>**[BQ28Z610](https://www.ti.com/product/BQ28Z610)** SLUSAS3D – APRIL 2014 – REVISED JUNE 2021 **[www.ti.com](https://www.ti.com)**





## **Figure 9-2. Wireless (Bluetooth) Speaker Application Block Diagram**

#### **9.2.1 Design Requirements (Default)**



#### **9.2.2 Detailed Design Procedure**

#### *9.2.2.1 Setting Design Parameters*

For the firmware settings needed for the design requirements, refer to the *[BQ28Z610 Technical Reference](https://www.ti.com/lit/pdf/SLUUA65) Manual* [\(SLUUA65\)](https://www.ti.com/lit/pdf/SLUUA65).

- To set the 2s1p battery pack, go to data flash *Configuration: DA Configuration* register's bit 0 (CC0) = 1.
- To set design capacity, set the data flash value to 4400 in the *Gas Gauging: Design: Design Capacity*  register.
- To set device chemistry, go to data flash *SBS Configuration: Data: Device Chemistry*. The BQSTUDIO software automatically populates the correct chemistry identification. This selection is derived from using the BQCHEM feature in the tools and choosing the option that matches the device chemistry from the list.
- To protect against cell overvoltage, set the data flash value to 4300 in *Protections: COV: Standard Temp*.
- To protect against cell undervoltage, set the data flash value to 2500 in the *Protections: CUV* register.
- To set the shutdown voltage to prevent further pack depletion due to low pack voltage, program *Power:*  **Shutdown: Shutdown** voltage = 2300.





- To protect against large charging currents when the AC adapter is attached, set the data flash value to 6000 in the *Protections: OCC: Threshold* register.
- To protect against large discharging currents when heavy loads are attached, set the data flash value to –6000 in the *Protections: OCD: Threshold* register.
- Program a short circuit delay timer and threshold setting to enable the operating the system for large short transient current pulses. These two parameters are under *Protections: ASCC: Threshold* = 100 for charging current. The discharge current setting is *Protections: ASCD:Threshold* = –100 mV.
- To prevent the cells from overcharging and adding a second level of safety, there is a register setting that will shut down the device if any of the cells voltage measurement is greater than the Safety Over Voltage setting for greater than the delay time. Set this data flash value to 4500 in *Permanent Fail: SOV: Threshold*.
- To disable the cell balancing feature, set the data flash value to 0 in *Settings: Configuration: Balancing Configuration*: bit 0 (CB).
- To enable the internal temperature and the external temperature sensors: Set *Settings:Configuration: Temperature Enable*: Bit 0 (TSInt) = 1 for the internal sensor; set Bit 1 (TS1) = 1 for the external sensor.
- To prevent charging of the battery pack if the temperature falls below 0°C, set *Protections: UTC:Threshold*   $= 0$ .
- To prevent discharging of the battery pack if the temperature falls below 0°C, set *Protections: UTD:Threshold* = 0.
- To provide required information to the smart chargers, the gas gauge must operate in BROADCAST mode. To enable this, set the [BCAST] bit in *Configuration: SBS Configuration* 2: Bit 0 [BCAST] = 1.

Each parameter listed for fault trigger thresholds has a delay timer setting associated for any noise filtering. These values, along with the trigger thresholds for fault detection, may be changed based upon the application requirements using the data flash settings in the appropriate register stated in the *[BQ28Z610 Technical](https://www.ti.com/lit/pdf/SLUUA65) [Reference Manual](https://www.ti.com/lit/pdf/SLUUA65)* (SLUUA65).

#### **9.2.3 Calibration Process**

The calibration of current, voltage, and temperature readings is accessible by writing 0xF081 or 0xF082 to *ManufacturerAccess()*. A detailed procedure is included in the *[BQ28Z610 Technical Reference Manual](https://www.ti.com/lit/pdf/SLUUA65)*  [\(SLUUA65\)](https://www.ti.com/lit/pdf/SLUUA65) in the *Calibration* section. The description allows for calibration of Cell Voltage Measurement Offset, Battery Voltage, Pack Voltage, Current Calibration, Coulomb Counter Offset, PCB Offset, CC Gain/Capacity Gain, and Temperature Measurement for both internal and external sensors.

#### **9.2.4 Gauging Data Updates**

When a battery pack enabled with the BQ28Z610 is first cycled, the value of *FullChargeCapacity()* updates several times. [Figure 9-3](#page-25-0) shows *RemainingCapacity()* and *FullChargeCapacity()*, and where those updates occur. As part of the Impedance Track algorithm, it is expected that *FullChargeCapacity()* may update at the end of charge, at the end of discharge, and at rest.



### <span id="page-25-0"></span>*9.2.4.1 Application Curve*



**Figure 9-3. Elapsed Time(s)**

## **Power Supply Requirements**

There are two inputs for this device, the PACK input and VC2. The PACK input can be an unregulated input from a typical AC adapter. This input should always be greater than the maximum voltage associated with the number of series cells configured. The input voltage for the VC2 pin will have a minimum of 2.2 V to a maximum of 26 V with the recommended external RC filter.

<span id="page-26-0"></span>

## **10 Layout**

## **10.1 Layout Guidelines**

- The layout for the high-current path begins at the PACK+ pin of the battery pack. As charge current travels through the pack, it finds its way through protection FETs, a chemical fuse, the Li-ion cells and cell connections, and the sense resistor, and then returns to the PACK– pin. In addition, some components are placed across the PACK+ and PACK– pins to reduce effects from electrostatic discharge.
- The N-channel charge and discharge FETs must be selected for a given application. Most portable battery applications are a good option for the CSD16412Q5A. These FETs are rated at 14-A, 25-V device with Rds(on) of 11 mΩ when the gate drive voltage is 10 V. The gates of all protection FETs are pulled to the source with a high-value resistor between the gate and source to ensure they are turned off if the gate drive is open. The capacitors (both 0.1 µF values) placed across the FETs are to help protect the FETs during an ESD event. The use of two devices ensures normal operation if one of them becomes shorted. For effective ESD protection, the copper trace inductance of the capacitor leads must be designed to be as short and wide as possible. Ensure that the voltage rating of both these capacitors is adequate to hold off the applied voltage if one of the capacitors becomes shorted.
- The quality of the Kelvin connections at the sense resistor is critical. The sense resistor must have a temperature coefficient no greater than 50 ppm in order to minimize current measurement drift with temperature. Choose the value of the sense resistor to correspond to the available overcurrent and shortcircuit ranges of the BQ28Z610. Select the smallest value possible in order to minimize the negative voltage generated on the BQ28Z610 VSS node(s) during a short circuit. This pin has an absolute minimum of –0.3 V. Parallel resistors can be used as long as good Kelvin sensing is ensured. The device is designed to support a 1-mΩ to 3-mΩ sense resistor.
- A pair of series 0.1-μF ceramic capacitors is placed across the PACK+ and PACK– pins to help in the mitigation of external electrostatic discharges. The two devices in series ensure continued operation of the pack if one of the capacitors becomes shorted. Optionally, a transorb such as the SMBJ2A can be placed across the pins to further improve ESD immunity.
- In reference to the gas gauge circuit the following features require attention for component placement and layout: Differential Low-Pass Filter, I2C communication, and PBI (Power Backup Input).
- The BQ28Z610 uses an integrating delta-sigma ADC for current measurements. Add a 100-Ω resistor from the sense resistor to the SRP and SRN inputs of the device. Place a 0.1-μF filter capacitor across the SRP and SRN inputs. Optional 0.1-μF filter capacitors can be added for additional noise filtering for each sense input pin to ground, if required for your circuit. Place all filter components as close as possible to the device. Route the traces from the sense resistor in parallel to the filter circuit. Adding a ground plane around the filter network can add additional noise immunity.



#### **Figure 10-1. BQ28Z610 Differential Filter**

• The BQ28Z610 has an internal LDO that is internally compensated and does not require an external decoupling capacitor. The PBI pin is used as a power supply backup input pin, providing power during brief transient power outages. A standard 2.2-μF ceramic capacitor is connected from the PBI pin to ground, as shown in application example.



<span id="page-27-0"></span>The I<sup>2</sup>C clock and data pins have integrated high-voltage ESD protection circuits; however, adding a Zener diode and series resistor provides more robust ESD performance. The I<sup>2</sup>C clock and data lines have an internal pull-down. When the gas gauge senses that both lines are low (such as during removal of the pack), the device performs auto-offset calibration and then goes into SLEEP mode to conserve power.

## **10.2 Layout Example**



 $\circ$  Via connects between two layers



<span id="page-28-0"></span>

## **11 Device and Documentation Support**

#### **11.1 Third-Party Products Disclaimer**

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#### **11.2 Documentation Support**

- *[BQ28Z610 Technical Reference Manual](https://www.ti.com/lit/pdf/SLUUA65)* (SLUUA65)
- *[Theory and Implementation of Impedance Track Battery Fuel-Gauging Algorithm Application Report](https://www.ti.com/lit/pdf/SLUA364)*  [\(SLUA364B\)](https://www.ti.com/lit/pdf/SLUA364)

#### **11.3 Receiving Notification of Documentation Updates**

To receive notification of documentation updates, navigate to the device product folder on [ti.com.](https://www.ti.com) Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

#### **11.4 Electrostatic Discharge Caution**



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

#### **11.5 Support Resources**

TI E2E™ [support forums](https://e2e.ti.com) are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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#### **11.7 Glossary**

[TI Glossary](https://www.ti.com/lit/pdf/SLYZ022) This glossary lists and explains terms, acronyms, and definitions.

## **Mechanical, Packaging, and Orderable Information**

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



## **PACKAGING INFORMATION**



**(1)** The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the  $\leq$ =1000ppm threshold requirement.

**(3)** MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

**(4)** There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

**(5)** Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

**(6)** Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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# **PACKAGE OPTION ADDENDUM**

www.ti.com 3-Jun-2021



**TEXAS** 

## **TAPE AND REEL INFORMATION**

**ISTRUMENTS** 





#### **QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**







www.ti.com 7-Dec-2024

# **PACKAGE MATERIALS INFORMATION**



\*All dimensions are nominal



## **TEXAS NSTRUMENTS**

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## **TUBE**



## **B - Alignment groove width**

\*All dimensions are nominal



# **DRZ0012A**

# **PACKAGE OUTLINE**

# **VSON - 1 mm max height**

PLASTIC QUAD FLATPACK- NO LEAD



NOTES:

- per ASME Y14.5M.<br>This drawing is subject to change without notice.
- 
- 



# **EXAMPLE BOARD LAYOUT**

# **DRZ0012A VSON - 1 mm max height**

PLASTIC QUAD FLATPACK- NO LEAD



NOTES: (continued)

- 
- on this view. It is recommended that vias under paste be filled, plugged or tented.



# **EXAMPLE STENCIL DESIGN**

# **DRZ0012A VSON - 1 mm max height**

PLASTIC QUAD FLATPACK- NO LEAD



6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



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